

LOW OFFSET VOLTAGE,LOW DRIFT OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

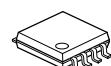
The NJM OP-07 is ultra-low input offset voltage and bias current, low drift and high gain operational amplifier with internal frequency compensation.

The NJM OP-07 is suitable for a precision instrumental amplifier.

■ PACKAGE OUTLINE



NJMOP-07D



NJMOP-07M

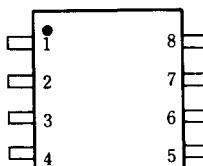


NJMOP-07E

■ FEATURES

- Low V_{IO} (60 μ V typ.)
- Low I_B (1.8nA typ.)
- Low Drift (unnull 0.5 μ V/ $^{\circ}$ C typ.)
(null 0.4 μ V/ $^{\circ}$ C typ.)
(0.4 μ V/M_o typ.)
- Wide Operating Voltage ($\pm 3V \sim \pm 22V$)
- Package Outline DIP8,DMP8,SOP8 JEDEC 150mil
- Bipolar Technology

■ PIN CONFIGURATION



NJMOP-07D

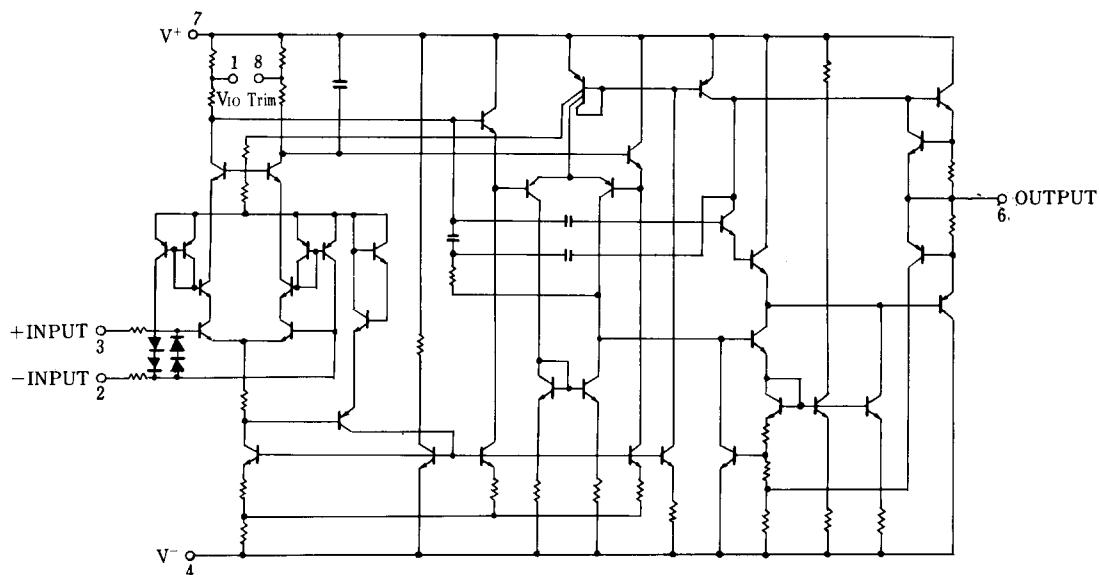
NJMOP-07M

NJMOP-07E

PIN FUNCTION

1. V_{IO} Trim
2. -INPUT
3. +INPUT
4. V^-
5. NC
6. OUTPUT
7. V^+
8. V_{IO} Trim

■ EQUIVALENT CIRCUIT



NJMOP-07

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺ /V ⁻	± 22	V
Input Voltage	V _I	± 22 (note1)	V
Differential Input Voltage	V _{ID}	± 30	V
Power Dissipation	P _D	(DIP8) 500(note2) (DMP8) 300(note2) / 430(note3) (SOP8) 300 (note2) / 640(note3)	mW
Storage Temperature Range	T _{stg}	-40~+125	°C
Operating Temperature Range	T _{opr}	-40~+85	°C
Output Current		continuous	

(note1) For supply voltage less than ±22V, the absolute maximum input voltage is equal to the supply voltage.

(note2) Device itself.

(note3) Mounted on the EIA/JEDEC standard board (76.2×114.3×1.6mm, two layer, FR-4).

■ ELECTRICAL CHARACTERISTICS

(Ta=+25°C, V⁺/V⁻=±15V)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}		-	60	150	µV
Long Term Stability		(note4,5)	-	0.4	2	µV/Mo
Input Offset Current	I _{IO}		-	0.8	6	nA
Input Bias Current	I _B		-	± 1.8	± 7	nA
Open Loop Output Resistance	R _O	V _O =0,I _O =0	-	60	-	Ω
Input Resistance	R _{ID}	(Differential Mode)	8	33	-	MΩ
Input Resistance	R _{IC}	(Common Mode)	-	120	-	GΩ
Input Common Mode Voltage Range	V _{ICM}		± 13	± 14	-	V
Common Mode Rejection Ratio	CMR	V _{CM} =±13V	100	120	-	dB
Supply Voltage Rejection Ratio	SVR	V ⁺ /V ⁻ =±3V~±18V	90	104	-	dB
Large Signal Voltage Gain 1	A _{V1}	R _L ≥2kΩ,V _O =±10V	101.5	112.0	-	dB
Large Signal Voltage Gain 2	A _{V2}	R _L =500Ω,V _O =±0.5V,V ⁺ /V ⁻ =±3V	100.0	112.0	-	dB
Maximum Output Voltage 1	V _{OM1}	R _L ≥10kΩ	± 12	± 13	-	V
Maximum Output Voltage 2	V _{OM2}	R _L >2kΩ	± 11.5	± 12.8	-	V
Maximum Output Voltage 3	V _{OM3}	R _L >1kΩ	-	± 12	-	V
Slew Rate	SR	R _L ≥2kΩ	-	0.17	-	V/µS
Unity Gain Bandwidth	f _T	A _{VCL} =1	-	0.5	-	MHz
Operating Current 1	I _{CC1}	V ⁺ /V ⁻ =±15V	-	2.7	5.0	mA
Operating Current 2	I _{CC2}	V ⁺ /V ⁻ =±3V	-	0.67	1.3	mA
Offset Adjustment Range	R _P	20kΩ	-	± 4	-	mV
Equivalent Input Noise Voltage	V _{NI}	0.1Hz~10Hz (note5)	-	0.38	0.65	µV _{P-P}
Equivalent Input Noise Voltage 1	e _{n1}	f ₀ =10Hz (note5)	-	10.5	20	nV/√Hz
Equivalent Input Noise Voltage 2	e _{n2}	f ₀ =100Hz (note5)	-	10.2	13.5	nV/√Hz
Equivalent Input Noise Voltage 3	e _{n3}	f ₀ =1kHz (note5)	-	9.8	11.5	nV/√Hz
Equivalent Input Noise Current	I _{NI}	0.1Hz~10Hz (note5)	-	15	35	pA _{P-P}
Equivalent Input Noise Current 1	i _{n1}	f ₀ =10Hz (note5)	-	0.35	0.9	pA/√Hz
Equivalent Input Noise Current 2	i _{n2}	f ₀ =100Hz (note5)	-	0.15	0.27	pA√/Hz
Equivalent Input Noise Current 3	i _{n3}	f ₀ =1kHz (note5)	-	0.13	0.18	pA/√Hz

■ ELECTRICAL CHARACTERISTICS

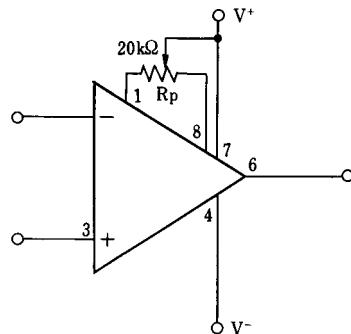
(0°C ≤ Ta ≤ 70°C, V⁺/V⁻ = ±15V)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	(note5)	-	85	250	µV
Average V _{IO} Drift (unnull)			-	0.5	1.8	µV/°C
Average V _{IO} Drift (null)		R _P =20kΩ, (note5)	-	0.4	1.6	µV/°C
Input Offset Current	I _{IO}	(note5)	-	1.6	8	nA
Average I _{IO} Drift			-	12	50	pA/°C
Input Bias Current	I _{IB}	(note5)	-	±2.2	±9	nA
Average I _{IB} Drift			-	18	50	pA/°C
Input Common Mode Voltage Range	V _{ICM}		±13	±13.5	-	V
Common Mode Rejection Ratio	CMR	V _{CM} =±13V	97	120	-	dB
Supply Voltage Rejection Ratio	SVR	V ⁺ /V ⁻ =±3V~±18V	86	120	-	dB
Voltage Gain	A _V	R _L ≥2kΩ, V _O =±10V	100	400	-	V/mV
Maximum Output Voltage	V _{OM}	R _L ≥2kΩ	±11	±12.6	-	V

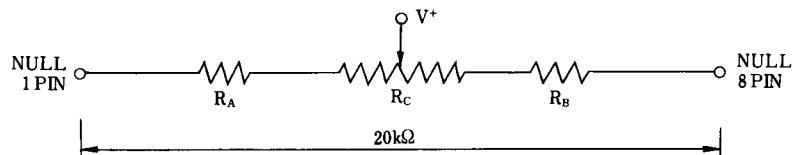
(note 4) Long Term Stability refers to the average trend line of V_{IO} vs. time over extended periods after the first 30 days of operation.

(note 5) According to the evaluation by NJRC, more than 90% of all these products can be guaranteed.

■ OFFSET ADJUSTMENT METHOD

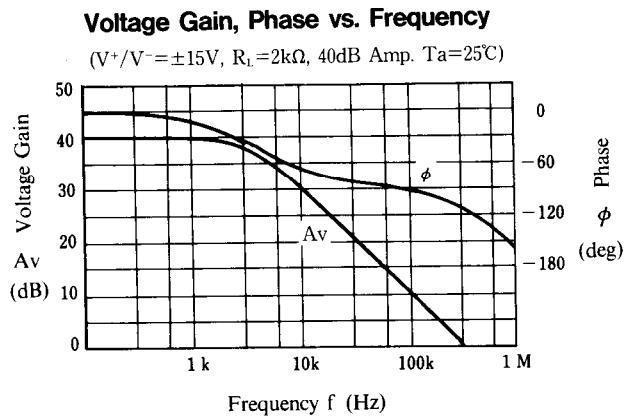
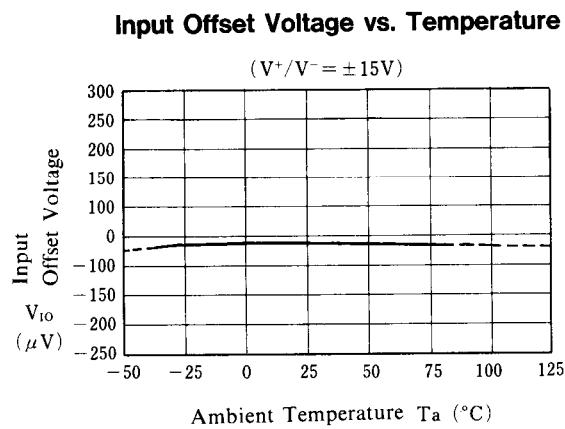
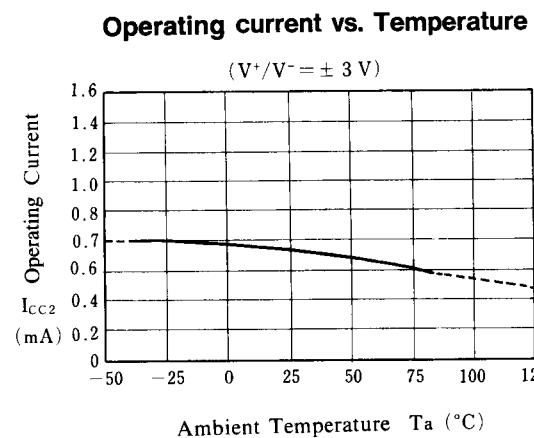
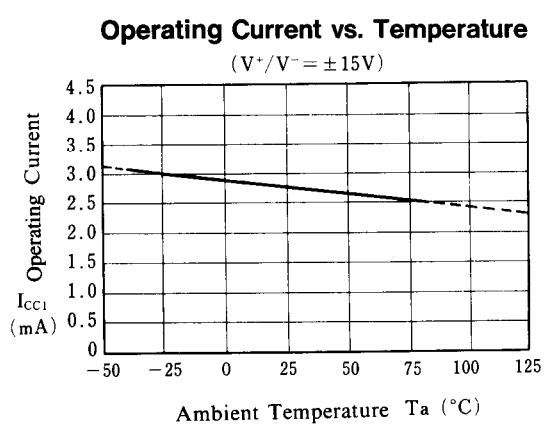
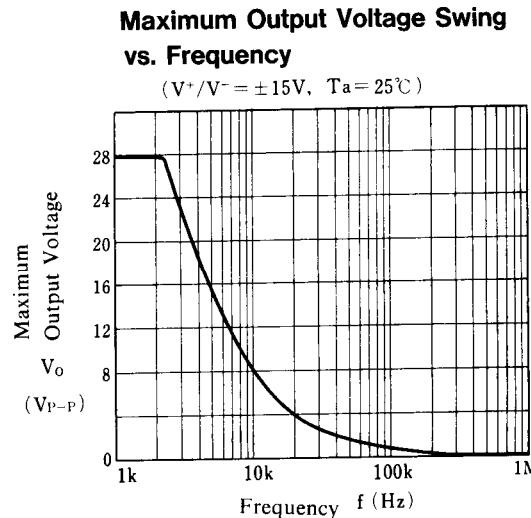
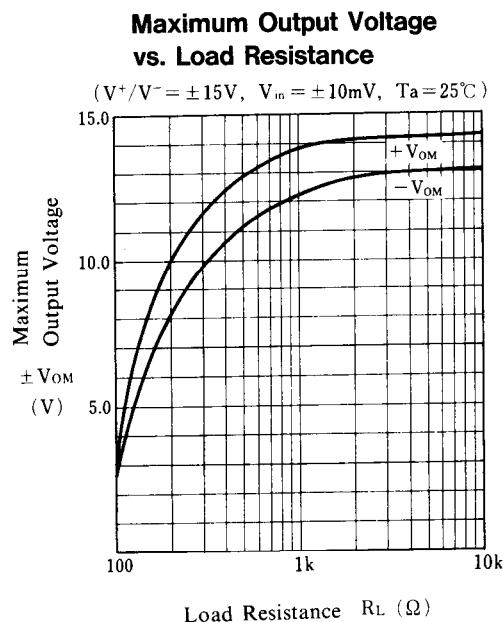


For making low sensitivity of change in the input offset voltage against resistance regulation of potentiometer
 (Easy case of offset adjustment)

* R_A, R_B Fixed 7.5kΩ, R_C adjustable 5.0kΩ* R_A, R_B, R_C are metalfilm resistors, R_C is more than 10 times winding.

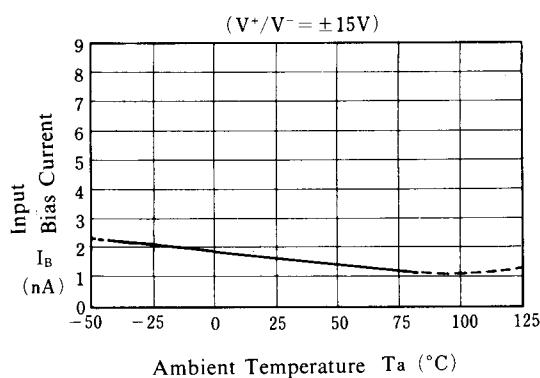
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■ TYPICAL CHARACTERISTICS

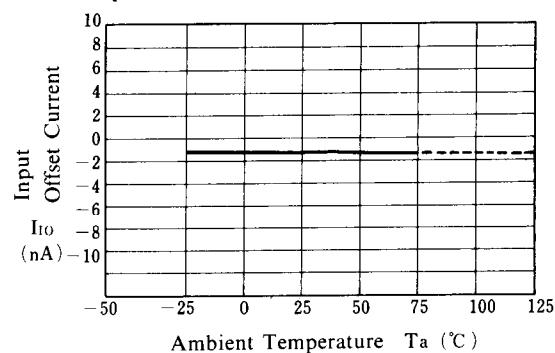


■ TYPICAL CHARACTERISTICS

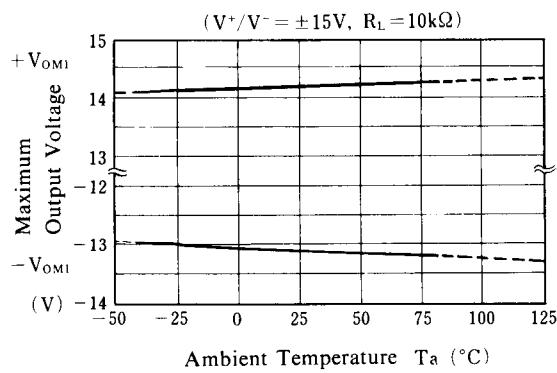
Input Bias Current vs. Temperature



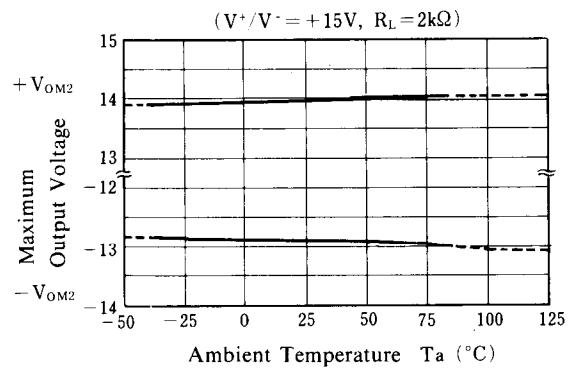
Input Offset Current vs. Temperarure



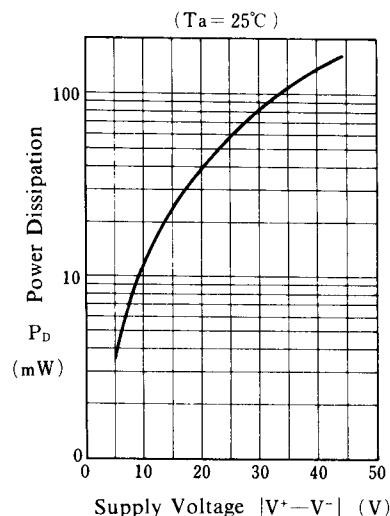
Maximum Output Voltage vs. Temperature



Maximum Output Voltage vs. Temperature



Power Dissipation vs. Supply Voltage



[CAUTION]
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